ALT-Series Analog TMR Sensors

**Equivalent Circuit**

![Equivalent Circuit Diagram]

**Features**
- Tunneling Magnetoresistive (TMR) technology
- Large signals (20 mV/V/mT typ.)
- ±10 mT (±100 Oe) linear range
- High linearity output (<1 %F.S. ±5 mT)
- Ultra-low temperature coefficient of output (±0.1 %/°C)
- Up to 300 kHz frequency bandwidth
- 20 kΩ typ. device resistance for low power
- Operation to near-zero voltage
- Up to 125 °C operating temperature
- Tiny TDFN6 package
- Standard (ALT005) and cross-axis (ALT025) versions

**Idealized Transfer Functions**

![Idealized Transfer Functions Diagram]

**Applications**
- Motion, speed, and position control
- Noncontact current sensing
- Mechatronics and robotics

**Description**

The ALT-series sensors are a Tunneling Magnetoresistance (TMR) analog bridge sensor with an extraordinary amount of signal and linear range.

The differential bridge output is bipolar, meaning it is positive for a positive field and negative for an opposite field polarity.

The Wheatstone bridge configuration allows the sensors to be pure ratiometric devices. They will operate properly at extremely low supply voltages, and the output signal will be proportional to the supply voltage.

The bridge signals are stable over a temperature range of −40 to 125 °C.

The sensor is available in a tiny TDFN6 package in tape and reel format.
### Absolute Maximum Ratings

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Min.</th>
<th>Typical</th>
<th>Max.</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply voltage</td>
<td>$V_{cc}$</td>
<td>7</td>
<td></td>
<td></td>
<td>Volts</td>
</tr>
<tr>
<td>Operating temperature $T_{min}$, $T_{max}$</td>
<td></td>
<td>−40</td>
<td>125</td>
<td></td>
<td>°C</td>
</tr>
<tr>
<td>Storage temperature</td>
<td></td>
<td>−65</td>
<td>150</td>
<td></td>
<td>°C</td>
</tr>
<tr>
<td>ESD (Human Body Model)(^1)</td>
<td></td>
<td></td>
<td>2000</td>
<td></td>
<td>Volts</td>
</tr>
<tr>
<td>Applied magnetic field(^2)</td>
<td>$H$</td>
<td>Unlimited</td>
<td></td>
<td></td>
<td>Tesla</td>
</tr>
<tr>
<td>Voltage from sensor connections to center pad</td>
<td></td>
<td>63</td>
<td></td>
<td></td>
<td>Volts DC</td>
</tr>
</tbody>
</table>

### Operating Specifications

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Min.</th>
<th>Typical</th>
<th>Max.</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>Operating temperature</td>
<td>$T$</td>
<td>−40</td>
<td>125</td>
<td></td>
<td>°C</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>$V_{cc}$</td>
<td>0</td>
<td>5.5</td>
<td></td>
<td>Volts</td>
</tr>
<tr>
<td>Offset voltage</td>
<td>$V_{offset}$</td>
<td>−20</td>
<td>20</td>
<td>55</td>
<td>mV/V</td>
</tr>
<tr>
<td>Device resistance</td>
<td>$R$</td>
<td>8</td>
<td>20</td>
<td>55</td>
<td>kΩ</td>
</tr>
<tr>
<td>Frequency bandwidth(^3)</td>
<td>$f$</td>
<td>DC</td>
<td>350</td>
<td></td>
<td>kHz</td>
</tr>
<tr>
<td>Operating field range(^2)</td>
<td>$H$</td>
<td>−10</td>
<td>10</td>
<td></td>
<td>mT</td>
</tr>
<tr>
<td>Saturation field(^2)</td>
<td>$H_{sat}$</td>
<td>30</td>
<td>1</td>
<td></td>
<td>mT</td>
</tr>
<tr>
<td>Sensitivity(^2)</td>
<td>$S_{en}$</td>
<td>6</td>
<td>20</td>
<td></td>
<td>mV/V/mT</td>
</tr>
<tr>
<td>Field Detectivity(^2)</td>
<td>$H_{min}$</td>
<td>30</td>
<td>0.7</td>
<td></td>
<td>nT/√Hz</td>
</tr>
<tr>
<td>Hysteresis(^5)</td>
<td>$H_c$</td>
<td></td>
<td>1</td>
<td></td>
<td>%F.S.</td>
</tr>
<tr>
<td>Linearity(^4,5)</td>
<td>$\pm 2$ mT, −40 − 85 °C</td>
<td>Lin</td>
<td>0.1</td>
<td>0.2 %F.S.</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$\pm 5$ mT, −40 − 85 °C</td>
<td></td>
<td>0.2</td>
<td>0.4%F.S.</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$\pm 2$ mT, −40 − 125 °C</td>
<td></td>
<td>0.2</td>
<td>0.5%F.S.</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$\pm 5$ mT, −40 − 125 °C</td>
<td></td>
<td>0.5</td>
<td>1%F.S.</td>
<td></td>
</tr>
<tr>
<td>Output at maximum field</td>
<td>$V_{max}$</td>
<td></td>
<td>400</td>
<td></td>
<td>mV/V</td>
</tr>
<tr>
<td>Temperature coefficient of device resistance(^6)</td>
<td>$TCR$</td>
<td>−0.08</td>
<td></td>
<td></td>
<td>%/°C</td>
</tr>
<tr>
<td>Temperature coefficient of output(^6)</td>
<td>$TCO$</td>
<td>−0.1</td>
<td>0</td>
<td>0.1</td>
<td>%/°C</td>
</tr>
<tr>
<td>Off-axis characteristic(^7)</td>
<td>$\cos^2(\beta)$</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

### Package Parameters

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Min.</th>
<th>Typical</th>
<th>Max.</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>Junction–ambient thermal resistance(^8)</td>
<td>$\theta_A$</td>
<td>320</td>
<td></td>
<td></td>
<td>°C/W</td>
</tr>
<tr>
<td>Power dissipation</td>
<td>$P_d$</td>
<td>500</td>
<td></td>
<td></td>
<td>mW</td>
</tr>
</tbody>
</table>

**Notes:**
1. Human Body Model (HBM) per JESD22-A114
2. 1 millitesla (mT) = 10\(^6\) nanotesla (nT) = 10 Gauss (G) = 10 Oersted (Oe) in air
3. Specified for amplitude reduction of −3 dB.
4. Full scale is defined as the operating field range.
5. Maximum deviation from best linear fit. Excludes contributions from hysteresis.
6. TCR is the device resistance change with temperature in constant applied field. TCO is the output change with temperature using either a constant current or constant voltage source to power the sensor.
7. Beta (\(\beta\)) is any angle from the sensitive axis.
8. Measured per JESD51 with ground pad not connected to circuit board.
Typical Performance Graphs

Figures 1 shows the response of the ALT-Series TMR sensors.

![Typical ALT0x5 output at various temperatures.](image)

**Cross-Axis Axis Directional Sensitivity**

The ALT-Series sensors have either cross-axis or standard axis sensitivity to magnetic fields. Cross-axis sensitivity corresponds to fields oriented from pad 1 to pad 6, and standard axis sensitivity corresponds to fields applied parallel to the pad 1 to pad 3 direction on the TDFN6 package. The ideal orientation for sensitivity is often determined by the orientation of the magnetic fields relative to PCB traces or system mechanical constraints.

The cross-axis configuration is useful in current sensor applications where current carrying circuit board traces oriented perpendicular to the sensitive direction avoid circuit board traces to the part and produce magnetic fields aligned the sensitive direction. The standard axis configuration is often more convenient for magnetometer applications such as magnet proximity sensing.

![Standard axis and cross-axis sensitivity for ALT-Series sensors.](image)
Bipolar
ALT-Series sensors are bipolar as shown in Figure 3. The sensor output changes sign with the magnetic field direction. This is ideal in applications such as current sensing and proximity sensing where AC waveforms are expected or the signal changes polarity. When the magnetic fields are oriented in the direction from pad 1 to pad 6 the sensor output \((V_{out^+} - V_{out^-})\) is positive for cross-axis sensitivity whereas the output is positive for fields oriented from pad 3 to pad 1 in the standard axis sensitivity configuration. The magnetic fields generated by the configuration in (a) and (b) produce the sensor output shown by the dot in (c).

![Figure 3. The ALT025 bipolar response.](image)

The output of the sensor follows a \(\cos (\theta)\) relationship, where \(\theta\) is the angle between the sensor’s positive output sensitive direction and the applied field.

In-Plane Sensitivity
Unlike Hall Effect or other sensors, the direction of sensitivity of the ALT-Series TMR sensor is in the plane of the package, which is more convenient for many applications. Two alternative permanent magnet orientations are shown in Figure 4.

![Figure 4. Planar magnetic sensitivity.](image)

Minimum Magnetic Field Detectivity
ALT-Series TMR sensors have a remarkably high sensitivity and low noise. These parameters define the minimum detectable field for the sensor. The noise spectrum of the ALT-series sensors follow a classical 1/f noise profile at low frequency and is white noise at high frequency. So the detectivity varies with frequency. For more information, see NVE’s application note on noise in TMR magnetometers, SB-00-101.
Illustrative Applications

_Dual-Supply Differential Amplifier_

The ALT-Series TMR sensor’s bipolar output is ideal for applications requiring positive and negative output voltages. The circuit below has a gain of five. A low-cost, low bias-current op amp allows large resistors to avoid loading the sensor bridge. The 1 MΩ input resistors are 100 times the 10 kΩ sensor output impedance to avoid loading.

![Figure 5. Dual-supply differential amplifier.](image)

_Single-Ended Instrumentation Amplifier_

TMR sensors have high output signals, but if amplification or a single-ended output is required, a circuit like the one below can be used. A gain of 2.5 amplifies the sensor’s typical maximum output of ±160 mV/V to 80% of rail-to-rail (one volt/volt), providing more usable signal without risk of saturating the amplifier for a sensor at the high end of the output signal range. A voltage divider provides a 2.5 V reference voltage to center the amplifier output with zero field.

![Figure 6. Single-ended analog sensor instrumentation amplifier.](image)
**Simple Direct Microcontroller Interfaces**

With their large output signals, ALT-Series TMR sensors can often interface directly to microcontrollers, even the 10-bit ADCs built into inexpensive microcontrollers such as Atmel AVRs®. Such microcontrollers are common in Arduino and other sensor interface boards. The ALT’s 20 kΩ typical device resistance provides 10 kΩ output impedances, ideal for direct interface to many microcontrollers:

![Figure 7. Typical direct microcontroller interface.](image)

**LED Field-Strength Indicator**

The ALT-Series sensor’s true bipolar output allows detection of field polarity. The op-amp circuit in the figure below can be used to detect the polarity of the magnetic field, and change brightness to indicate field strength at a glance:

![Figure 8. LED brightness indicates the magnetic field and color indicates polarity.](image)

In this circuit, a positive field turns on the red LED, and a negative field turns on the yellow LED. The 250 kΩ potentiometer is optional to correct for sensor offset.
Noncontact Current Sensing
With low hysteresis, high linearity at low fields, and high speed, the ALT025 is ideal for noncontact current measurement. Due to its convenient in-plane sensitivity, it can be mounted directly over PCB traces. The sensor measures the current by detecting the magnetic field generated by the current through the trace.

The ALT025 features cross-axis sensitivity, so it is able to detect current traces directly beneath the part for maximum accuracy. These sensors have a wide linear range, so they are solutions for a wide variety of current requirements. By tailoring the PCB trace to the application, the ALT025 can detect currents from 0.1 mA to 250 A.

Two typical high-resolution current sensing configurations are shown below. The current trace runs directly under the ALT025 on a single side of the PCB.

For these configurations, the generated magnetic field is easy to calculate with Ampere’s Law:

\[ H = 5nI \]  
[“H” in oersteds and “I” in amps. “n” is the number of turns.]

For high current sensing, larger traces are required. The sensor is typically mounted opposite a high current trace on a standard PCB, as shown in Figure 10. In this case, the width of the trace is significant, and a formula can be obtained by breaking the trace into a finite element array of thin traces, and calculating the field from each array element.

\[ H = \frac{4I}{w} \arctan \left( \frac{w}{2d} \right) \]  
[“H” in oersteds, “I” in amps, “d” in millimeters includes half of the package thickness, and “w” in millimeters.]

To simplify these calculations, we have a free, Web-based application with these formulas to calculate magnetic fields and sensor outputs in this application:

www.nve.com/spec/calculators.php#tabs-Current-Sensing

To help with the design of high current traces for current sensing applications, see our application note, which provides a comprehensive guide.

### TDFN6 Package (-10 suffix)

**Notes:**
- Dimensions in millimeters.
- Soldering profile per JEDEC J-STD-020C, MSL 1.

### ALT-Series Sensors Functional Diagram and Pinout

<table>
<thead>
<tr>
<th>Pin</th>
<th>Symbol</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>V_{out+}</td>
<td>Positive bridge output (increases with field).</td>
</tr>
<tr>
<td>2</td>
<td>NC</td>
<td>No internal connection.</td>
</tr>
<tr>
<td>3</td>
<td>GND</td>
<td>Negative bridge supply or ground.</td>
</tr>
<tr>
<td>4</td>
<td>V_{out-}</td>
<td>Negative bridge output (decreases with field).</td>
</tr>
<tr>
<td>5</td>
<td>NC</td>
<td>No internal connection.</td>
</tr>
<tr>
<td>6</td>
<td>V_{cc}</td>
<td>Positive bridge supply.</td>
</tr>
</tbody>
</table>

**Center Pad**
- Internally connected to leadframe
**Part Numbering**

**ALT025-10E**

**Base Part**
ALT = Analog TMR Magnetometer Sensors

**Sensitivity Direction**
- 00 = Standard Axis
- 02 = Cross-Axis

**Sensitivity Code**
- 5 = 10 mT Linear Range

**Package Type**
- 10 = TDFN6
- E = RoHS

**Available Parts**

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Marking</th>
</tr>
</thead>
<tbody>
<tr>
<td>ALT005-10E</td>
<td>FHB</td>
</tr>
<tr>
<td>ALT025-10E</td>
<td>FHC</td>
</tr>
</tbody>
</table>

**Bare Circuit Board**

NVE offers a bare circuit board designed for easy connections to TDFN6 sensors such as ALT-Series sensors:

AG035-06: TDFN6 connection board
(1.57” x 0.25” / 40 mm x 6 mm; actual size).

**Current Sensor Evaluation Board**

This demonstration board shows the ALT025’s remarkable linear range and accuracy for up to ±200 A noncontact current measurement:

AG905-07E: ALT025-10E High-Current Demonstration Board
(3” x 2.065” / 76 mm x 52 mm; actual size).
Revision History

SB-00-102 – Rev. E
April 2020
Change
• Increased maximum resistance rating for lower power.

SB-00-102 – Rev. D
November 2019
Change
• Added ALT005 part for standard-axis sensitivity.
• Updates and clarifications for standard axis and cross-axis sensitivities.

SB-00-102 – Rev. C
August 2019
Change
• Revised Fig. 4 (p. 4).
• Added AG905-07E current sensing demonstration board (p. 9).
• Minor typographical changes.

SB-00-102 – Rev. B
June 2019
Change
• Added part marking.
• Added minimum sensor detectivity.
• Clarified definition of full scale and corrected offset specification.

SB-00-102 – Rev. A
June 2019
Change
• Clarified connections on application circuits.
• Increased typical sensitivity consistent with test data.

SB-00-102 – Prelim
June 2019
Change
• Preliminary release.
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